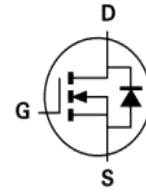
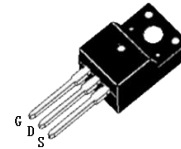


MAIN CHARACTERISTICS	
$I_D$	18A
$V_{DSS}$	500V
$R_{DS(on)-typ}$ (@ $V_{GS}=10V$ )	0.27 $\Omega$



- ### FEATURES
- Fast Switching
  - Low ON Resistance
  - Low Gate Charge
  - 100% Single Pulse avalanche energy Test



TO-220F

- ### APPLICATIONS
- Power switch circuit of adaptor and charger.

- ### MECHANICAL DATA
- Case: Molded plastic
  - Mounting Position: Any
  - Molded Plastic: UL Flammability Classification Rating 94V-0
  - Lead free in compliance with EU RoHS 2011/65/EU directive
  - Solder bath temperature 275°C maximum,10s per JESD 22-B106

Product specification classification			
Part Number	Package	Mode Name	Pack
CS18N50A8	TO-220F (1.3mm)	CS18N50A	Tube

### Maximum Ratings at Tc=25°C unless otherwise specified

Characteristics	Symbol	Value	Unit
		220F	
Drain-Source Voltage	$V_{DS}$	500	V
Gate-Source Voltage	$V_{GS}$	±30	V
Continue Drain Current	$I_D$	18	A
Pulsed Drain Current (Note1)	$I_{DM}$	72	A
Power Dissipation	$P_D$	43	W
Single Pulse Avalanche Energy (Note1)	$E_{AS}$	1000	mJ
Operating Temperature Range	$T_J$	150	°C
Storage Temperature Range	$T_{STG}$	-55 to +150	°C
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.92	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	°C/W

Note1:Pulse test: 300 μs pulse width, 2 % duty cycle

### Electrical Characteristics at Tc=25°C unless otherwise specified

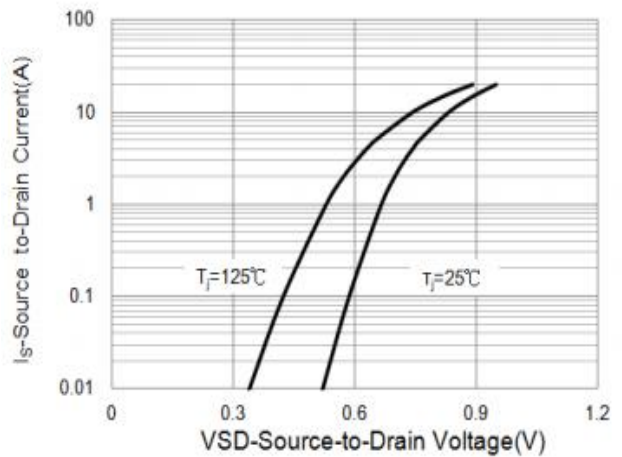
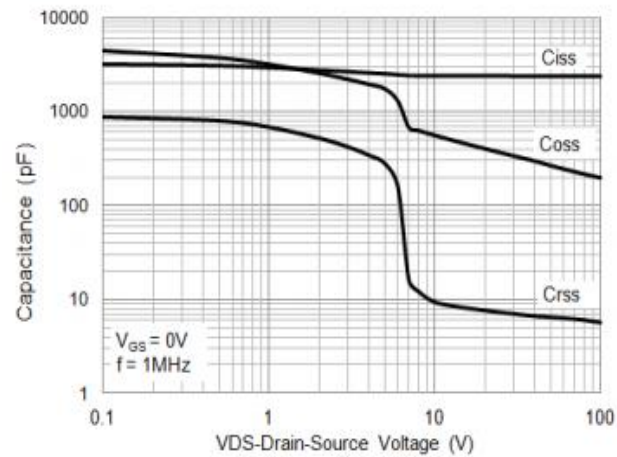
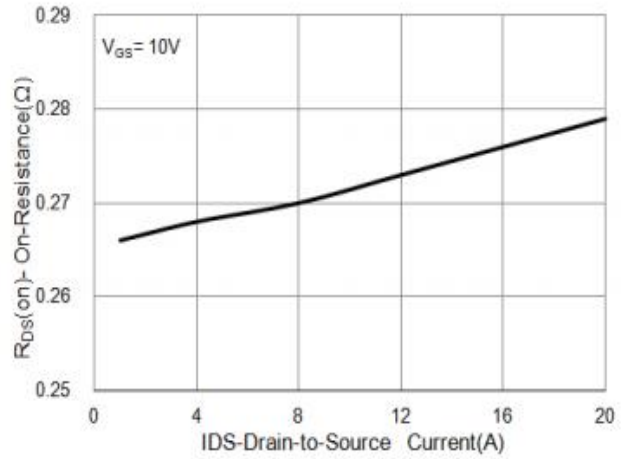
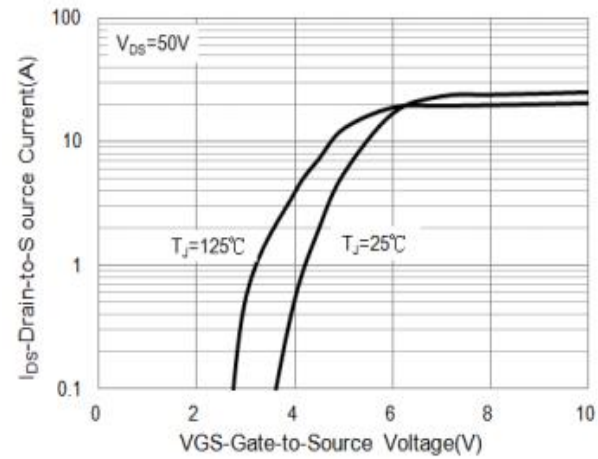
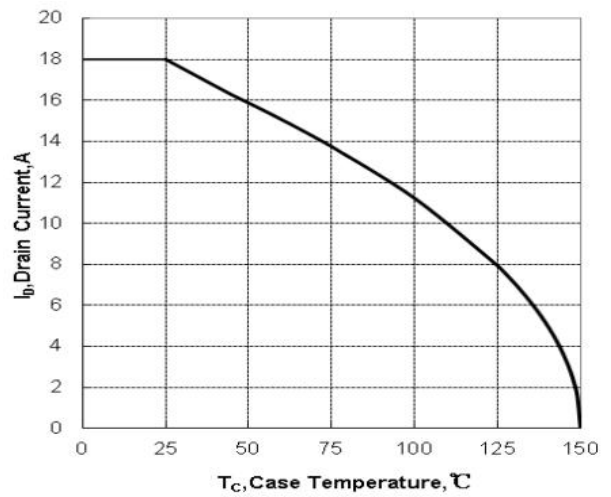
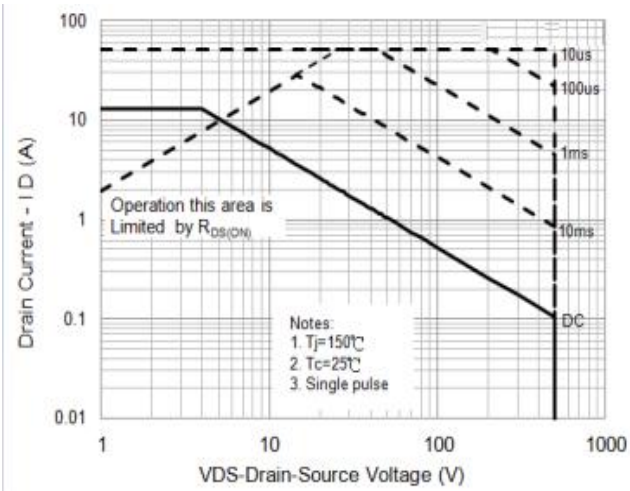
Characteristics	Test Condition	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$	$BV_{DSS}$	500	538	-	V
Drain-Source Leakage Current	$V_{DS} = 500 V, V_{GS} = 0 V$	$I_{DSS}$	-	-	1	μA
Gate Leakage Current	$V_{GS} = \pm 30 V, V_{DS} = 0 V$	$I_{GSS}$	-	-	±100	nA
Gate-Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	$V_{GS(th)}$	2	-	4	V
Drain-Source On-State Resistance	$V_{GS} = 10 V, I_D = 8 A$	$R_{DS(on)}$	-	0.27	0.36	Ω
Forward Transconductance	$V_{DS} = 15 V, I_D = 8 A$	$g_{fs}$	-	6	-	S
Input Capacitance	$V_{GS} = 0 V, V_{DS} = 25 V,$ $f = 1 MHz$	$C_{iss}$	-	2250	-	pF
Output Capacitance		$C_{oss}$	-	360	-	pF
Reverse Transfer Capacitance		$C_{rss}$	-	7.2	-	pF
Turn-on Delay Time(Note2)	$I_D = 18 A, V_{DD} = 250 V,$ $R_G = 25 \Omega$	$t_d(ON)$	-	60	-	ns
Rise Time(Note2)		$t_r$	-	132	-	ns
Turn-Off Delay Time(Note2)		$t_d(OFF)$	-	116	-	ns
Fall Time(Note2)		$t_f$	-	76	-	ns
Total Gate Charge(Note2)	$I_D = 20 A, V_{DD} = 400 V,$ $V_{GS} = 10 V$	$Q_G$	-	71	-	nC
Gate to Source Charge(Note2)		$Q_{GS}$	-	13	-	nC
Gate to Drain Charge(Note2)		$Q_{GD}$	-	12	-	nC

### Source-Drain Diode Characteristics at Ta=25°C unless otherwise specified

Characteristics	Test Condition	Symbol	Min.	Typ.	Max.	Unit
Maximun Body-Diode Continuous Current		$I_S$	-	-	18	A
Maximun Body-Diode Pulsed Current(Note2)		$I_{SM}$	-	-	72	A
Drain-Source Diode Forward Voltage	$I_{SD} = 18 A$	$V_{SD}$	-	-	1.5	V
Reverse Recovery Time(Note2)	$I_{SD} = 18 A, V_{GS} = 0 V,$ $dI_F / dt = 100 A/\mu s$	$t_{rr}$	-	449	-	ns
Reverse Recovery Charge(Note2)		$Q_{rr}$	-	4.8	-	μC

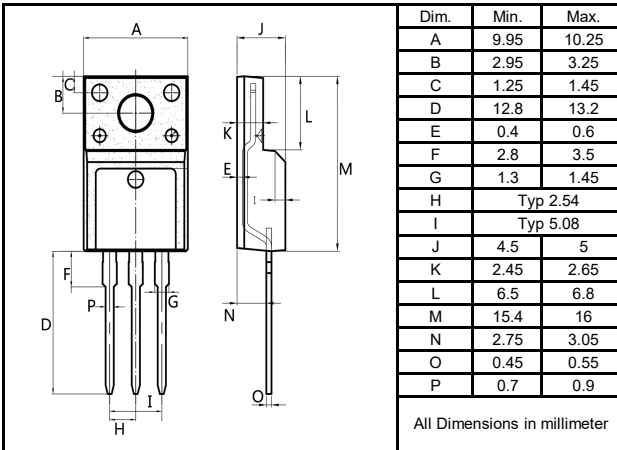
Note2:Pulse test: 300 μs pulse width, 2 % duty cycle

### RATINGS AND CHARACTERISTIC CURVES

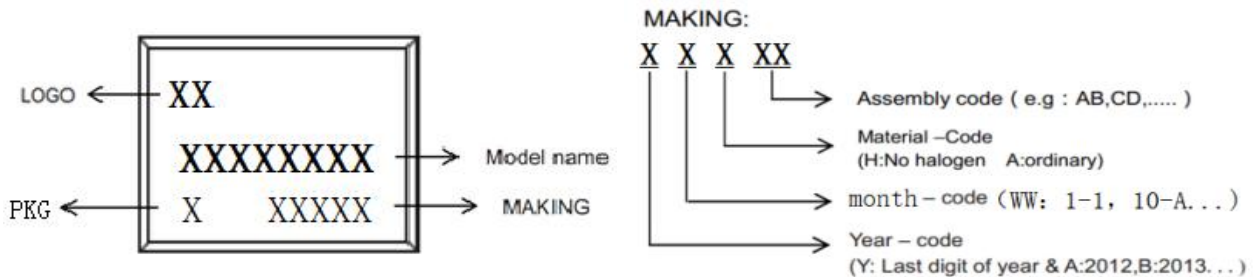


### Package Outline Dimensions millimeters

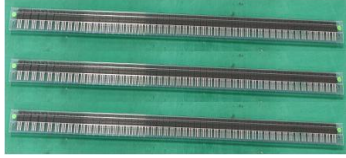
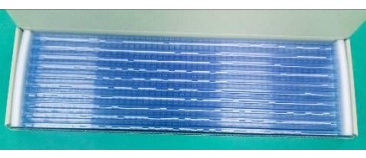

TO-220F



### Marking on the body



### packing instruction

PKG	最小包装	内盒	外箱
TO-220F	 50pcs/管	 1000pcs/盒	 5000pcs/箱

### Notice

All product, product specifications and data are subject to change without notice to improve. The right to explain is owned by LINGXUN electronics company.

Confirm that operation temperature is within the specified range described in the product specification. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

LINGXUN electronics shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.